



500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

MAX5033

General Description

The MAX5033 easy-to-use, high-efficiency, high-voltage, step-down DC-DC converter operates from an input voltage up to 76V and consumes only 270 μ A quiescent current at no load. This pulse-width modulated (PWM) converter operates at a fixed 125kHz switching frequency at heavy loads, and automatically switches to pulse-skipping mode to provide low quiescent current and high efficiency at light loads. The MAX5033 includes internal frequency compensation simplifying circuit implementation. The device uses an internal low-on-resistance, high-voltage, DMOS transistor to obtain high efficiency and reduce overall system cost. This device includes undervoltage lockout, cycle-by-cycle current limit, hiccup-mode output short-circuit protection, and thermal shutdown.

The MAX5033 delivers up to 500mA output current. The output current may be limited by the maximum power dissipation capability of the package. External shutdown is included, featuring 10 μ A (typ) shutdown current. The MAX5033A/B/C versions have fixed output voltages of 3.3V, 5V, and 12V, respectively, while the MAX5033D features an adjustable output voltage, from 1.25V to 13.2V.

The MAX5033 is available in space-saving 8-pin SO and 8-pin plastic DIP packages and operates over the automotive (-40°C to +125°C) temperature range.

Applications

Automotive
Consumer Electronics
Industrial
Distributed Power

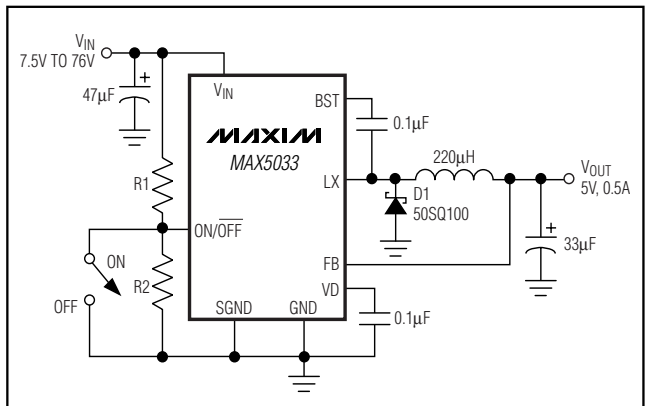
Features

- ◆ Wide 7.5V to 76V Input Voltage Range
- ◆ Fixed (3.3V, 5V, 12V) and Adjustable (1.25V to 13.2V) Voltage Versions
- ◆ 500mA Output Current
- ◆ Efficiency Up to 94%
- ◆ Internal 0.4 Ω High-Side DMOS FET
- ◆ 270 μ A Quiescent Current at No Load, 10 μ A Shutdown Current
- ◆ Internal Frequency Compensation
- ◆ Fixed 125kHz Switching Frequency
- ◆ Thermal Shutdown and Short-Circuit Current Limit
- ◆ 8-Pin SO and PDIP Packages

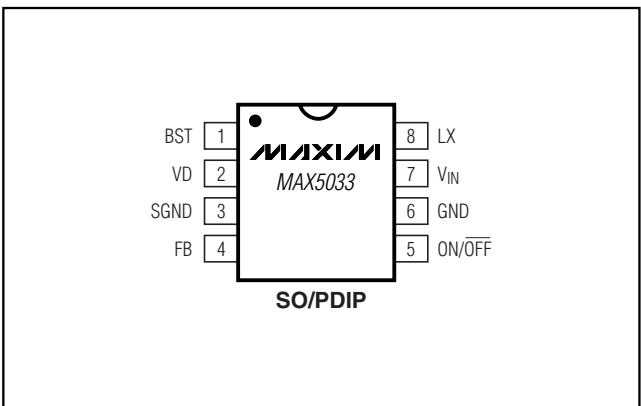
Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	OUTPUT VOLTAGE (V)
MAX5033AUSA	0°C to +85°C	8 SO	3.3
MAX5033AUPA	0°C to +85°C	8 PDIP	
MAX5033AASA	-40°C to +125°C	8 SO	
MAX5033BUSA	0°C to +85°C	8 SO	5.0
MAX5033BUPA	0°C to +85°C	8 PDIP	
MAX5033BASA	-40°C to +125°C	8 SO	
MAX5033CUSA	0°C to +85°C	8 SO	12
MAX5033CUPA	0°C to +85°C	8 PDIP	
MAX5033CASA	-40°C to +125°C	8 SO	
MAX5033DUSA	0°C to +85°C	8 SO	ADJ
MAX5033DUPA	0°C to +85°C	8 PDIP	
MAX5033DASA	-40°C to +125°C	8 SO	

Typical Operating Circuit



Pin Configuration



500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to GND, unless otherwise specified.)

V _{IN}	-0.3V to +80V
SGND	-0.3V to +0.3V
LX	-0.8V to (V _{IN} + 0.3V)
BST	-0.3V to (V _{IN} + 10V)
BST (transient < 100ns)	-0.3V to (V _{IN} + 15V)
BST to LX	-0.3V to +10V
BST to LX (transient < 100ns)	-0.3V to +15V
ON/OFF	-0.3V to (V _{IN} + 0.3V)
VD	-0.3V to +12V
FB	
MAX5033A/MAX5033B/MAX5033C	-0.3V to +15V
MAX5033D	-0.3V to +12V

V _{OUT} Short-Circuit Duration	Indefinite
VD Short-Circuit Duration	Indefinite
Continuous Power Dissipation (T _A = +70°C)	
8-Pin PDIP (derate 9.1mW/°C above +70°C)	727mW
8-Pin SO (derate 5.9mW/°C above +70°C)	471mW
Operating Temperature Range	
MAX5033_U_	0°C to +85°C
MAX5033_A_	-40°C to +125°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS (MAX5033_U_)

(V_{IN} = +12V, V_{ON/OFF} = +12V, I_{OUT} = 0, T_A = 0°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C. See the Typical Application Circuit.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Voltage Range	V _{IN}	MAX5033A	7.5		76.0	V
		MAX5033B	7.5		76.0	
		MAX5033C	15		76	
		MAX5033D	7.5		76.0	
Undervoltage Lockout	UVLO			5.2		V
Output Voltage	V _{OUT}	MAX5033A, V _{IN} = 7.5V to 76V, I _{OUT} = 20mA to 500mA	3.185	3.3	3.415	V
		MAX5033B, V _{IN} = 7.5V to 76V, I _{OUT} = 20mA to 500mA	4.85	5.0	5.15	
		MAX5033C, V _{IN} = 15V to 76V, I _{OUT} = 20mA to 500mA	11.64	12	12.36	
Feedback Voltage	V _{FB}	V _{IN} = 7.5V to 76V, MAX5033D	1.192	1.221	1.250	V
Efficiency	η	V _{IN} = 12V, I _{LOAD} = 500mA, MAX5033A		86		%
		V _{IN} = 12V, I _{LOAD} = 500mA, MAX5033B		90		
		V _{IN} = 24V, I _{LOAD} = 500mA, MAX5033C		94		
		V _{IN} = 12V, V _{OUT} = 5V, I _{LOAD} = 500mA, MAX5033D		90		
Quiescent Supply Current	I _Q	V _{FB} = 3.5V, V _{IN} = 7.5V to 76V, MAX5033A		270	440	μA
		V _{FB} = 5.5V, V _{IN} = 7.5V to 76V, MAX5033B		270	440	
		V _{FB} = 13V, V _{IN} = 15V to 76V, MAX5033C		270	440	
		V _{FB} = 1.3V, MAX5033D		270	440	
Shutdown Current	I _{SHDN}	V _{ON/OFF} = 0V, V _{IN} = 7.5V to 76V		10	45	μA
Peak Switch Current Limit	I _{LIM}	(Note 1)	0.95	1.5	2.1	A
Switch Leakage Current	I _{OL}	V _{IN} = 76V, V _{ON/OFF} = 0V, V _{LX} = 0V		1		μA

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

MAX5033

ELECTRICAL CHARACTERISTICS (MAX5033_U_) (continued)

($V_{IN} = +12V$, $V_{ON/OFF} = +12V$, $I_{OUT} = 0$, $T_A = 0^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$. See the Typical Application Circuit.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Switch On-Resistance	R _{DS(ON)}	I _{SWITCH} = 500mA		0.4	0.80	Ω
PFM Threshold	I _{PFM}	Minimum switch current in any cycle	35	65	95	mA
FB Input Bias Current	I _B	MAX5033D	-150	+0.01	+150	nA
ON/OFF CONTROL INPUT						
ON/OFF Input-Voltage Threshold	V _{ON/OFF}	Rising trip point	1.53	1.69	1.85	V
ON/OFF Input-Voltage Hysteresis	V _{HYST}			100		mV
ON/OFF Input Current	I _{ON/OFF}	V _{ON/OFF} = 0V to V _{IN}		10	150	nA
OSCILLATOR						
Oscillator Frequency	f _{OSC}		109	125	135	kHz
Maximum Duty Cycle	D _{MAX}	MAX5033D		95		%
VOLTAGE REGULATOR						
Regulator Output Voltage	V _D	V _{IN} = 8.5V to 76V, I _L = 0mA	6.9	7.8	8.8	V
Dropout Voltage		7.5V ≤ V _{IN} ≤ 8.5V, I _L = 1mA		2.0		V
Load Regulation	ΔV _D /ΔI _{VD}	0 to 5mA		150		Ω
PACKAGE THERMAL CHARACTERISTICS						
Thermal Resistance (Junction to Ambient)	θ _{JA}	SO package (JEDEC 51)		170		°C/W
		DIP package (JEDEC 51)		110		
THERMAL SHUTDOWN						
Thermal-Shutdown Junction Temperature	T _{SH}			+160		°C
Thermal-Shutdown Hysteresis	T _{HYST}			20		°C

ELECTRICAL CHARACTERISTICS (MAX5033_A_)

($V_{IN} = +12V$, $V_{ON/OFF} = +12V$, $I_{OUT} = 0$, $T_A = T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$. See the Typical Application Circuit.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Voltage Range	V_{IN}	MAX5033A	7.5		76.0	V
		MAX5033B	7.5		76.0	
		MAX5033C	15		76	
		MAX5033D	7.5		76.0	
Undervoltage Lockout	UVLO			5.2		V
Output Voltage	V_{OUT}	MAX5033A, $V_{IN} = 7.5V$ to $76V$, $I_{OUT} = 20mA$ to $500mA$	3.185	3.3	3.415	V
		MAX5033B, $V_{IN} = 7.5V$ to $76V$, $I_{OUT} = 20mA$ to $500mA$	4.825	5.0	5.175	
		MAX5033C, $V_{IN} = 15V$ to $76V$, $I_{OUT} = 20mA$ to $500mA$	11.58	12	12.42	

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

ELECTRICAL CHARACTERISTICS (MAX5033_A_ _)

($V_{IN} = +12V$, $V_{ON/OFF} = +12V$, $I_{OUT} = 0$, $T_A = T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$. See the *Typical Application Circuit*.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Feedback Voltage	V _{FB}	V _{IN} = 7.5V to 76V, MAX5033D	1.192	1.221	1.250	V
Efficiency	η	V _{IN} = 12V, I _{LOAD} = 500mA, MAX5033A	86		%	
		V _{IN} = 12V, I _{LOAD} = 500mA, MAX5033B	90			
		V _{IN} = 24V, I _{LOAD} = 500mA, MAX5033C	94			
		V _{IN} = 12V, V _{OUT} = 5V, I _{LOAD} = 500mA, MAX5033D	90			
Quiescent Supply Current	I _Q	V _{FB} = 3.5V, V _{IN} = 7.5V to 76V, MAX5033A	270		μA	
		V _{FB} = 5.5V, V _{IN} = 7.5V to 76V, MAX5033B	270			
		V _{FB} = 13V, V _{IN} = 15V to 76V, MAX5033C	270			
		V _{FB} = 1.3V, MAX5033D	270			
Shutdown Current	I _{SHDN}	V _{ON/OFF} = 0V, V _{IN} = 7.5V to 76V	10		45	μA
Peak Switch Current Limit	I _{LIM}	(Note 1)	0.95	1.5	2.20	A
Switch Leakage Current	I _{OL}	V _{IN} = 76V, V _{ON/OFF} = 0V, V _{LX} = 0V	1			μA
Switch On-Resistance	R _{DS(ON)}	I _{SWITCH} = 500mA	0.4		0.80	Ω
PFM Threshold	I _{PFM}	Minimum switch current in any cycle	35	65	110	mA
FB Input Bias Current	I _B	MAX5033D	-150	+0.01	+150	nA
ON/OFF CONTROL INPUT						
ON/OFF Input-Voltage Threshold	V _{ON/OFF}	Rising trip point	1.50	1.69	1.85	V
ON/OFF Input-Voltage Hysteresis	V _{HYST}		100			mV
ON/OFF Input Current	I _{ON/OFF}	V _{ON/OFF} = 0V to V _{IN}	10		150	nA
OSCILLATOR						
Oscillator Frequency	f _{OSC}		105	125	137	kHz
Maximum Duty Cycle	D _{MAX}	MAX5033D	95			%
VOLTAGE REGULATOR						
Regulator Output Voltage	V _D	V _{IN} = 8.5V to 76V, I _L = 0mA	6.5	7.8	9.0	V
Dropout Voltage		7.5V ≤ V _{IN} ≤ 8.5V, I _L = 1mA	2.0			V
Load Regulation	ΔV _D /ΔI _D	0 to 5mA	150			Ω
PACKAGE THERMAL CHARACTERISTICS						
Thermal Resistance (Junction to Ambient)	θ _{JA}	SO package (JEDEC 51)	170		°C/W	
		DIP package (JEDEC 51)	110			
THERMAL SHUTDOWN						
Thermal-Shutdown Junction Temperature	T _{SH}		+160			°C
Thermal-Shutdown Hysteresis	T _{HYST}		20			°C

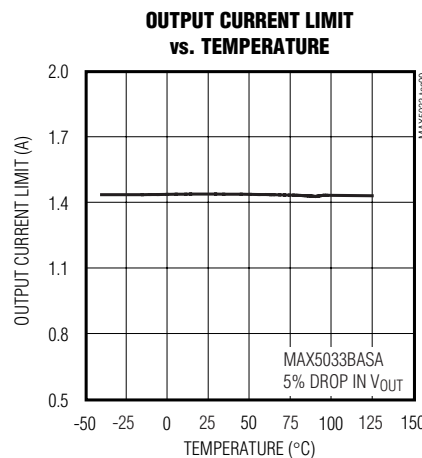
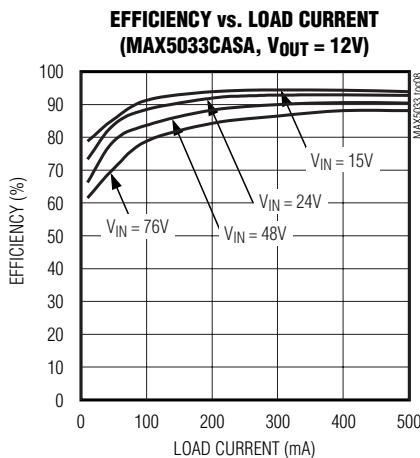
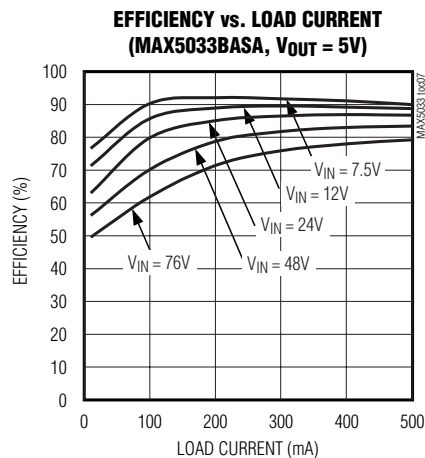
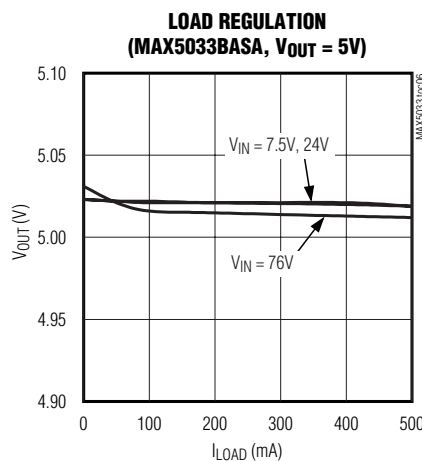
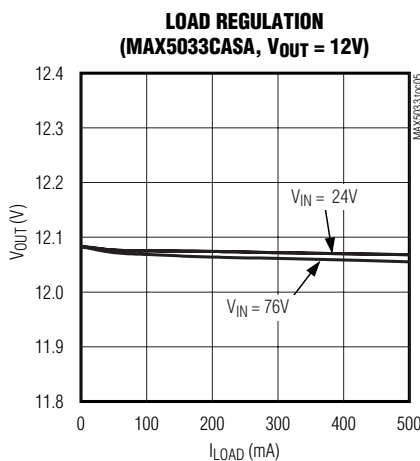
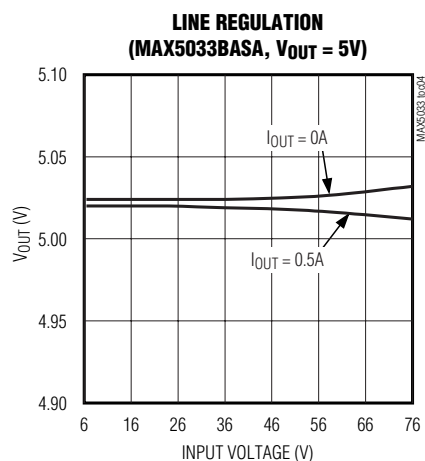
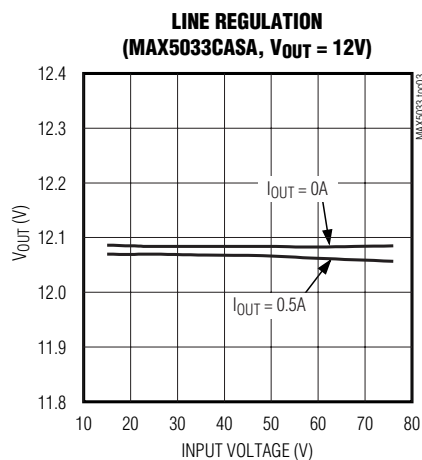
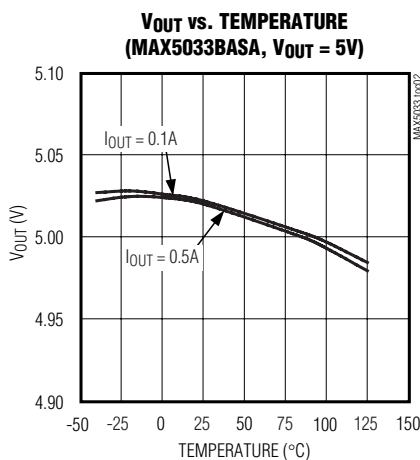
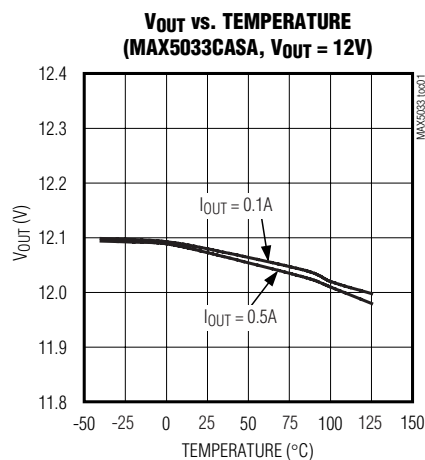
Note 1: Switch current at which the current limit is activated.

Note 2: All limits at $-40^{\circ}C$ are guaranteed by design, not production tested.

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

Typical Operating Characteristics

($V_{IN} = 12V$, $V_{ON/OFF} = 12V$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$. See the *Typical Application Circuit*, if applicable.)

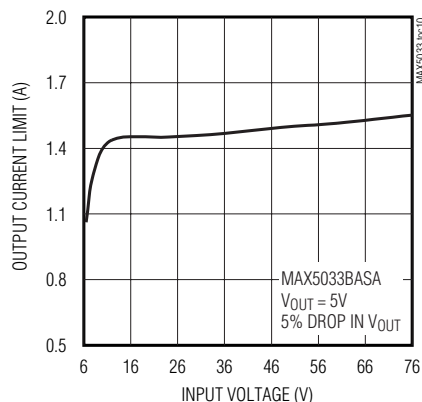


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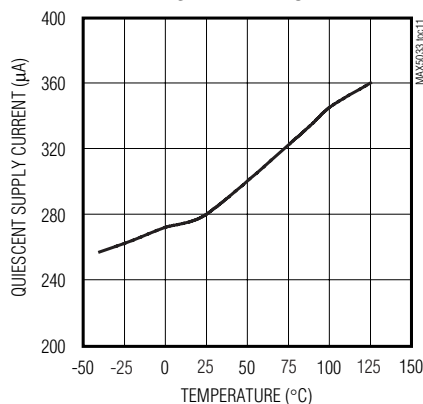
Typical Operating Characteristics (continued)

($V_{IN} = 12V$, $V_{ON/OFF} = 12V$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$. See the *Typical Application Circuit*, if applicable.)

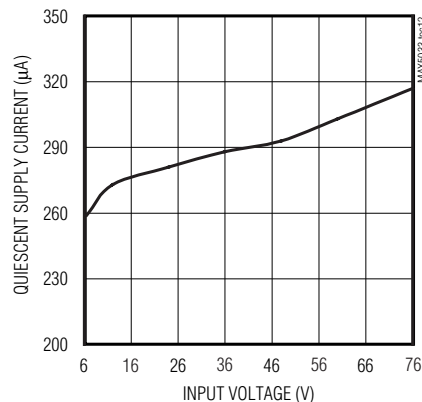
**OUTPUT CURRENT LIMIT
vs. INPUT VOLTAGE**



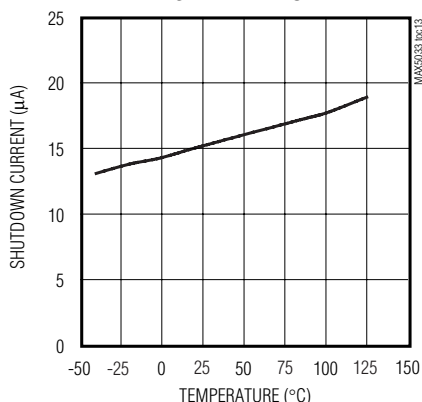
**QUIESCENT SUPPLY CURRENT
vs. TEMPERATURE**



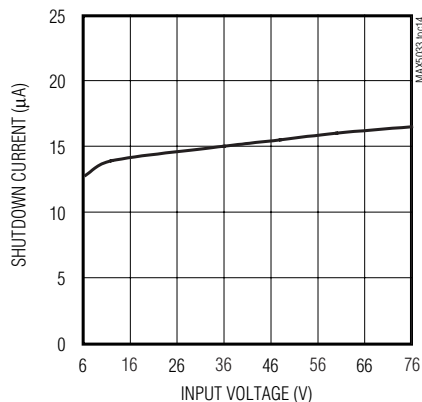
**QUIESCENT SUPPLY CURRENT
vs. INPUT VOLTAGE**



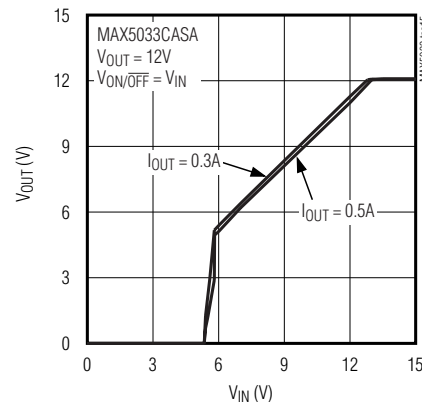
**SHUTDOWN CURRENT
vs. TEMPERATURE**



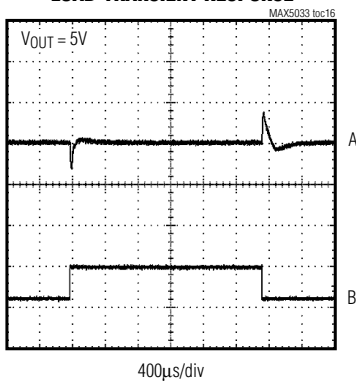
**SHUTDOWN CURRENT
vs. INPUT VOLTAGE**



**OUTPUT VOLTAGE
vs. INPUT VOLTAGE**

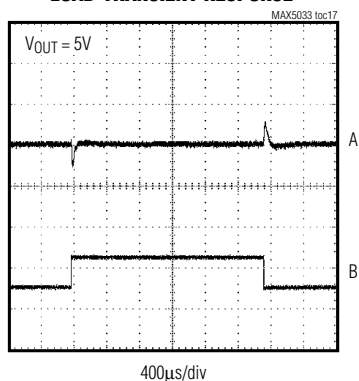


**MAX5033BASA
LOAD-TRANSIENT RESPONSE**



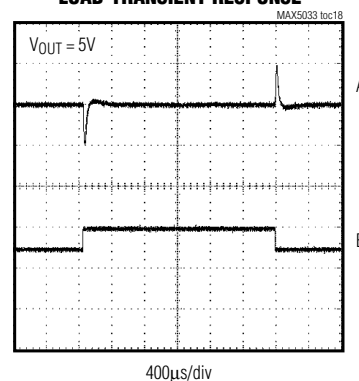
A: V_{OUT} , 200mV/div, AC-COUPLED
B: I_{OUT} , 500mA/div, 100mA TO 500mA

**MAX5033BASA
LOAD-TRANSIENT RESPONSE**



A: V_{OUT} , 100mV/div, AC-COUPLED
B: I_{OUT} , 200mA/div, 100mA TO 250mA

**MAX5033BASA
LOAD-TRANSIENT RESPONSE**



A: V_{OUT} , 100mV/div, AC-COUPLED
B: I_{OUT} , 500mA/div, 250mA TO 500mA

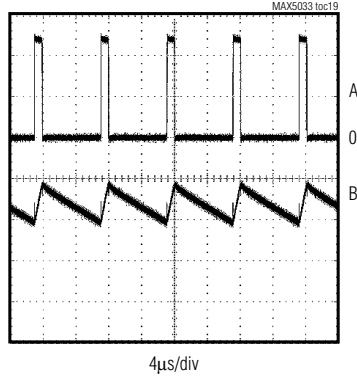
500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

MAX5033

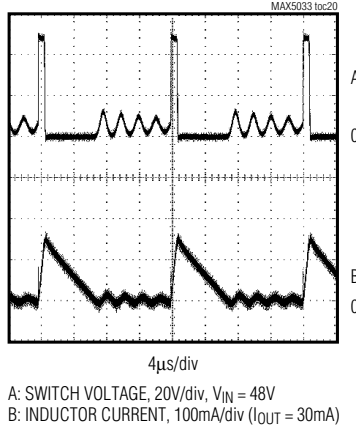
Typical Operating Characteristics (continued)

($V_{IN} = 12V$, $V_{ON/OFF} = 12V$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$. See the *Typical Application Circuit*, if applicable.)

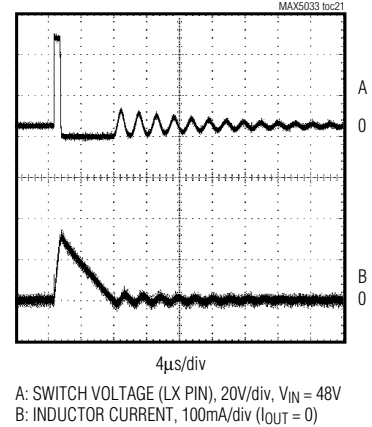
**MAX5033BASA
LX WAVEFORMS**



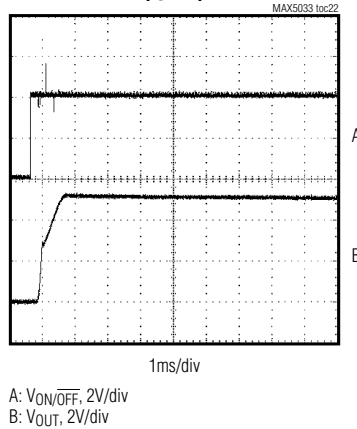
MAX5033BASA LX WAVEFORMS



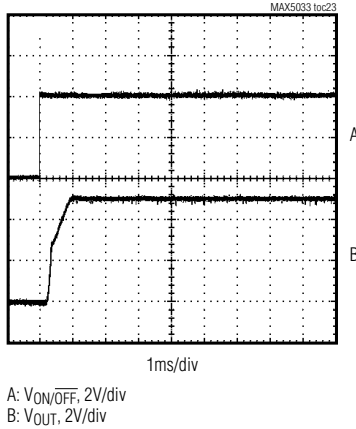
MAX5033BASA LX WAVEFORMS



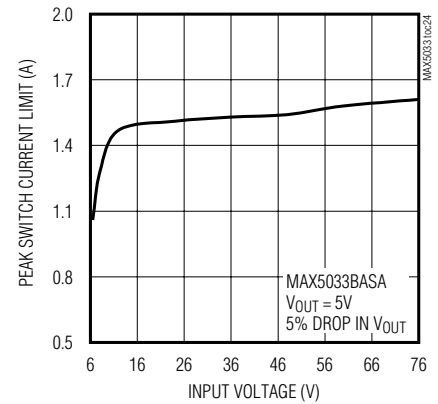
**MAX5033BASA STARTUP WAVEFORM
($I_O = 0$)**



**MAX5033BASA STARTUP WAVEFORM
($I_O = 0.5A$)**



**PEAK SWITCH CURRENT LIMIT
vs. INPUT VOLTAGE**

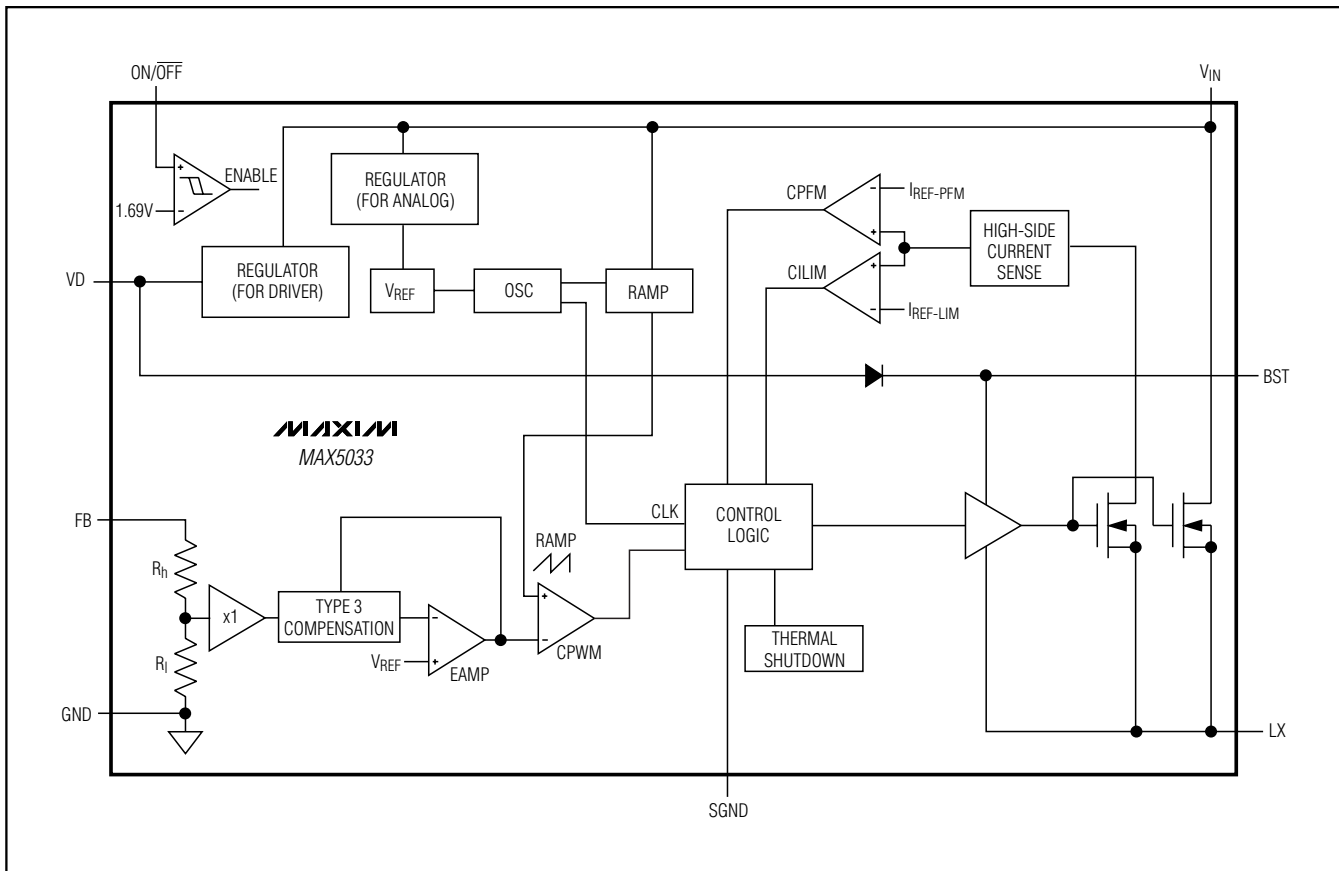


500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

Pin Description

PIN	NAME	FUNCTION
1	BST	Boost Capacitor Connection. Connect a 0.1 μ F ceramic capacitor from BST to LX.
2	VD	Internal Regulator Output. Bypass VD to GND with a 0.1 μ F ceramic capacitor.
3	SGND	Internal Connection. SGND must be connected to GND.
4	FB	Output Sense Feedback Connection. For fixed output voltage (MAX5033A, MAX5033B, MAX5033C), connect FB to V _{OUT} . For adjustable output voltage (MAX5033D), use an external resistive voltage-divider to set V _{OUT} . V _{FB} regulating set point is 1.22V.
5	ON/OFF	Shutdown Control Input. Pull ON/OFF low to put the device in shutdown mode. Drive ON/OFF high for normal operation.
6	GND	Ground
7	V _{IN}	Input Voltage. Bypass V _{IN} to GND with a low-ESR capacitor as close to the device as possible.
8	LX	Source Connection of Internal High-Side Switch

Simplified Block Diagram



MAX5033

9

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

The MAX5033 features internal compensation for optimum closed-loop bandwidth and phase margin. With the preset compensation, it is strongly advised to sense the output immediately after the primary LC.

Inductor Selection

The choice of an inductor is guided by the voltage difference between V_{IN} and V_{OUT} , the required output current, and the operating frequency of the circuit. Use an inductor with a minimum value given by:

$$L = \frac{(V_{IN} - V_{OUT}) \times D}{0.3 \times I_{OUTMAX} \times f_{SW}}$$

where: $D = V_{OUT}/V_{IN}$, I_{OUTMAX} is the maximum output current required, and f_{SW} is the operating frequency of 125kHz. Use an inductor with a maximum saturation current rating equal to at least the peak switch current limit (I_{LIM}). Use inductors with low DC resistance for higher efficiency.

Selecting a Rectifier

The MAX5033 requires an external Schottky rectifier as a freewheeling diode. Connect this rectifier close to the device using short leads and short PC board traces. Choose a rectifier with a continuous current rating greater than the highest expected output current. Use a rectifier with a voltage rating greater than the maximum expected input voltage, V_{IN} . Use a low forward-voltage Schottky rectifier for proper operation and high efficiency. Avoid higher than necessary reverse-voltage Schottky rectifiers that have higher forward-voltage drops. Use a Schottky rectifier with forward-voltage drop (V_{FB}) less than 0.45V at +25°C and maximum

load current to avoid forward biasing of the internal body diode (LX to ground). Internal body-diode conduction may cause excessive junction temperature rise and thermal shutdown. Use Table 1 to choose the proper rectifier at different input voltages and output current.

Input Bypass Capacitor

The discontinuous input-current waveform of the buck converter causes large ripple currents in the input capacitor. The switching frequency, peak inductor current, and the allowable peak-to-peak voltage ripple that reflects back to the source dictate the capacitance requirement. The MAX5033 high switching frequency allows the use of smaller-value input capacitors.

The input ripple is comprised of ΔV_Q (caused by the capacitor discharge) and ΔV_{ESR} (caused by the ESR of the capacitor). Use low-ESR aluminum electrolytic capacitors with high ripple-current capability at the input. Assuming that the contribution from the ESR and capacitor discharge is equal to 90% and 10%, respectively, calculate the input capacitance and the ESR required for a specified ripple using the following equations:

$$ESR_{IN} = \frac{\Delta V_{ESR}}{\left(I_{OUT} + \frac{\Delta I_L}{2}\right)}$$

$$C_{IN} = \frac{I_{OUT} \times D(1-D)}{\Delta V_Q \times f_{SW}}$$

where

$$\Delta I_L = \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{V_{IN} \times f_{SW} \times L}$$

$$D = \frac{V_{OUT}}{V_{IN}}$$

I_{OUT} is the maximum output current of the converter and f_{SW} is the oscillator switching frequency (125kHz). For example, at $V_{IN} = 48V$ and $V_{OUT} = 3.3V$, the ESR and input capacitance are calculated for the input peak-to-peak ripple of 100mV or less, yielding an ESR and capacitance value of 130mΩ and 27μF, respectively.

Low-ESR, ceramic, multilayer chip capacitors are recommended for size-optimized application. For ceramic capacitors, assume the contribution from ESR and capacitor discharge is equal to 10% and 90%, respectively.

The input capacitor must handle the RMS ripple current without significant rise in temperature. The maximum capacitor RMS current occurs at about 50% duty cycle.

Table 1. Diode Selection

V_{IN} (V)	DIODE PART NUMBER	MANUFACTURER
7.5 to 36	15MQ040N	IR
	B240A	Diodes, Inc.
	B240	Central Semiconductor
	MBRS240, MBRS1540	ON Semiconductor
7.5 to 56	30BQ060	IR
	B360A	Diodes, Inc.
	CMSH3-60	Central Semiconductor
	MBRD360, MBR3060	ON Semiconductor
7.5 to 76	50SQ100, 50SQ80	IR
	MBRM5100	Diodes, Inc.

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

Ensure that the ripple specification of the input capacitor exceeds the worst-case capacitor RMS ripple current. Use the following equations to calculate the input capacitor RMS current:

$$I_{CRMS} = \sqrt{I_{PRMS}^2 - I_{AVGIN}^2}$$

where

$$I_{PRMS} = \sqrt{\left(I_{PK}^2 + I_{DC}^2 + (I_{PK} \times I_{DC})\right) \times \frac{D}{3}}$$

$$I_{AVGIN} = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times \eta}$$

$$I_{PK} = I_{OUT} + \frac{\Delta I_L}{2}, I_{DC} = I_{OUT} - \frac{\Delta I_L}{2}$$

$$\text{and } D = \frac{V_{OUT}}{V_{IN}}$$

I_{PRMS} is the input switch RMS current, I_{AVGIN} is the input average current, and η is the converter efficiency.

The ESR of aluminum electrolytic capacitors increases significantly at cold temperatures. Use a 1 μ F or greater value ceramic capacitor in parallel with the aluminum electrolytic input capacitor, especially for input voltages below 8V.

Output Filter Capacitor

The worst-case peak-to-peak and RMS capacitor ripple current, allowable peak-to-peak output ripple voltage, and the maximum deviation of the output voltage during load steps determine the capacitance and the ESR requirements for the output capacitors.

The output capacitance and its ESR form a zero, which improves the closed-loop stability of the buck regulator. Choose the output capacitor so the ESR zero frequency (f_z) occurs between 20kHz to 40kHz. Use the following equation to verify the value of f_z . Capacitors with 100m Ω to 250m Ω ESR are recommended to ensure the closed-loop stability while keeping the output ripple low.

$$f_z = \frac{1}{2 \times \pi \times C_{OUT} \times ESR_{OUT}}$$

The output ripple is comprised of ΔV_{OQ} (caused by the capacitor discharge) and ΔV_{OESR} (caused by the ESR of the capacitor). Use low-ESR tantalum or aluminum electrolytic capacitors at the output. Assuming that the contributions from the ESR and capacitor discharge equal 80% and 20%, respectively, calculate the output

capacitance and the ESR required for a specified ripple using the following equations:

$$ESR_{OUT} = \frac{\Delta V_{OESR}}{\Delta I_L}$$

$$C_{OUT} \approx \frac{\Delta I_L}{2.2 \times \Delta V_{OQ} \times f_{SW}}$$

The MAX5033 has an internal soft-start time (t_{SS}) of 400 μ s. It is important to keep the output rise time at startup below t_{SS} to avoid output overshoot. The output rise time is directly proportional to the output capacitor. Use 68 μ F or lower capacitance at the output to control the overshoot below 5%.

In a dynamic load application, the allowable deviation of the output voltage during the fast-transient load dictates the output capacitance value and the ESR. The output capacitors supply the step load current until the controller responds with a greater duty cycle. The response time ($t_{RESPONSE}$) depends on the closed-loop bandwidth of the converter. The resistive drop across the capacitor ESR and capacitor discharge cause a voltage droop during a step load. Use a combination of low-ESR tantalum and ceramic capacitors for better transient load and ripple/noise performance. Keep the maximum output-voltage deviation above the tolerable limits of the electronics being powered. Assuming a 50% contribution from the output capacitance discharge and the ESR drop, use the following equations to calculate the required ESR and capacitance value:

$$ESR_{OUT} = \frac{\Delta V_{OESR}}{I_{STEP}}$$

$$C_{OUT} = \frac{I_{STEP} \times t_{RESPONSE}}{\Delta V_{OQ}}$$

where I_{STEP} is the load step and $t_{RESPONSE}$ is the response time of the controller. Controller response time is approximately one-third of the reciprocal of the closed-loop unity-gain bandwidth, 20kHz (typ).

PC Board Layout Considerations

Proper PC board layout is essential. Minimize ground noise by connecting the anode of the Schottky rectifier, the input bypass-capacitor ground lead, and the output filter-capacitor ground lead to a single point (star-

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

Application Circuits

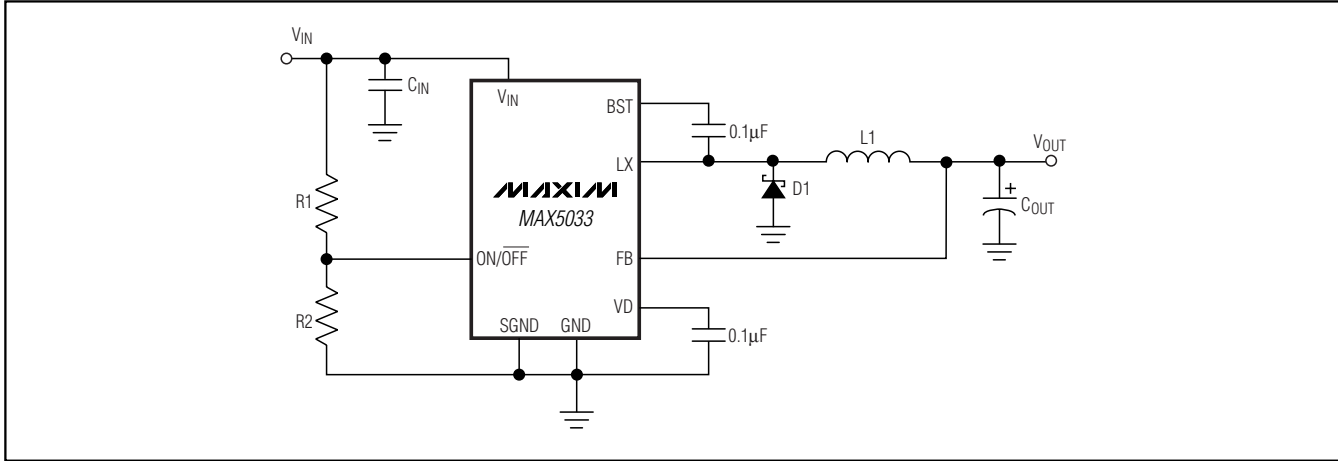


Figure 2. Fixed Output Voltages

Table 2. Typical External Components Selection (Circuit of Figure 2)

V _{IN} (V)	V _{OUT} (V)	I _{OUT} (A)	EXTERNAL COMPONENTS
7.5 to 76	3.3	0.5	C _{IN} = 47µF, Panasonic, EEVFK2A470Q C _{OUT} = 47µF, Vishay Sprague, 594D476X_016C2T C _{BST} = 0.1µF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 384kΩ ±1%, 0805 D1 = 50SQ100, IR L1 = 150µH, Coilcraft Inc., DO5022P-154
7.5 to 76	5	0.5	C _{IN} = 47µF, Panasonic, EEVFK2A470Q C _{OUT} = 33µF, Vishay Sprague, 594D336X_016C2T C _{BST} = 0.1µF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 384kΩ ±1%, 0805 D1 = 50SQ100, IR L1 = 220µH, Coilcraft Inc., DO5022P-224
15 to 76	12	0.5	C _{IN} = 47µF, Panasonic, EEVFK2A470Q C _{OUT} = 15µF, Vishay Sprague, 594D156X_025C2T C _{BST} = 0.1µF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 384kΩ ±1%, 0805 D1 = 50SQ100, IR L1 = 330µH, Coilcraft Inc., DO5022P-334

ground configuration). A ground plane is required. Minimize lead lengths to reduce stray capacitance, trace resistance, and radiated noise. In particular, place the Schottky rectifier diode right next to the

device. Also, place BST and VD bypass capacitors very close to the device. Use the PC board copper plane connecting to V_{IN} and LX for heatsinking.

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

MAX5033

Table 2. Typical External Components Selection (Circuit of Figure 2) (continued)

V _{IN} (V)	V _{OUT} (V)	I _{OUT} (A)	EXTERNAL COMPONENTS
9 to 14	3.3	0.5	C _{IN} = 100μF, Panasonic, EEVFK1E101P C _{OUT} = 47μF, Vishay Sprague, 594D476X_016C2T C _{BST} = 0.1μF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 274kΩ ±1%, 0805 D1 = B220/A, Diodes Inc. L1 = 150μH, Coilcraft Inc., DO5022P-154
	5	0.5	C _{IN} = 100μF, Panasonic, EEVFK1E101P C _{OUT} = 33μF, Vishay Sprague, 594D336X_016C2T C _{BST} = 0.1μF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 274kΩ ±1%, 0805 D1 = B220/A, Diodes Inc. L1 = 220μH, Coilcraft Inc., DO5022P-224
18 to 36	3.3	0.5	C _{IN} = 100μF, Panasonic, EEVFK1H101P C _{OUT} = 47μF, Vishay Sprague, 594D476X_016C2T C _{BST} = 0.1μF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 130kΩ ±1%, 0805 D1 = B240/A, Diodes Inc. L1 = 150μH, Coilcraft Inc., DO5022P-154
	5	0.5	C _{IN} = 100μF, Panasonic, EEVFK1H101P C _{OUT} = 33μF, Vishay Sprague, 594D336X_016C2T C _{BST} = 0.1μF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 130kΩ ±1%, 0805 D1 = B240/A, Diodes Inc. L1 = 220μH, Coilcraft Inc., DO5022P-224
	12	0.5	C _{IN} = 100μF, Panasonic, EEVFK1H101P C _{OUT} = 15μF, Vishay Sprague, 594D156X_025C2T C _{BST} = 0.1μF, 0805 R1 = 1MΩ ±1%, 0805 R2 = 130kΩ ±1%, 0805 D1 = B240/A, Diodes Inc. L1 = 330μH, Coilcraft Inc., DO5022P-334

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

Table 3. Component Suppliers

SUPPLIER	PHONE	FAX	WEBSITE
AVX	843-946-0238	843-626-3123	www.avxcorp.com
Coilcraft	847-639-6400	847-639-1469	www.coilcraft.com
Diodes Incorporated	805-446-4800	805-446-4850	www.diodes.com
Nichicon	858-824-1515	858-824-1525	www.nichicon.com
Panasonic	714-373-7366	714-737-7323	www.panasonic.com
Sanyo	619-661-6835	619-661-1055	www.sanyo.com
TDK	847-803-6100	847-390-4405	www.component.tdk.com
Vishay	402-563-6866	402-563-6296	www.vishay.com

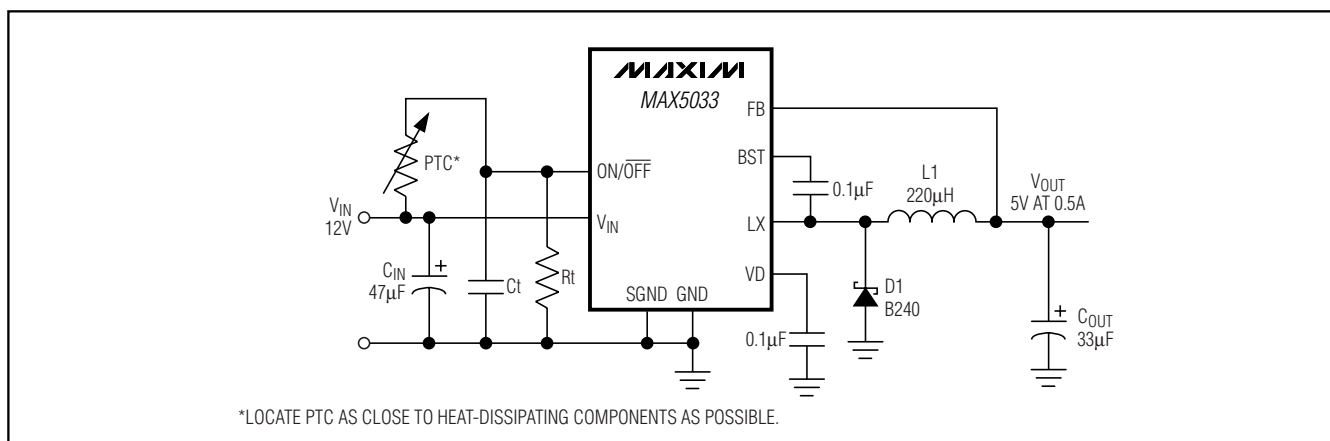


Figure 3. Load Temperature Monitoring with ON/OFF (Requires Accurate VIN)

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

MAX5033

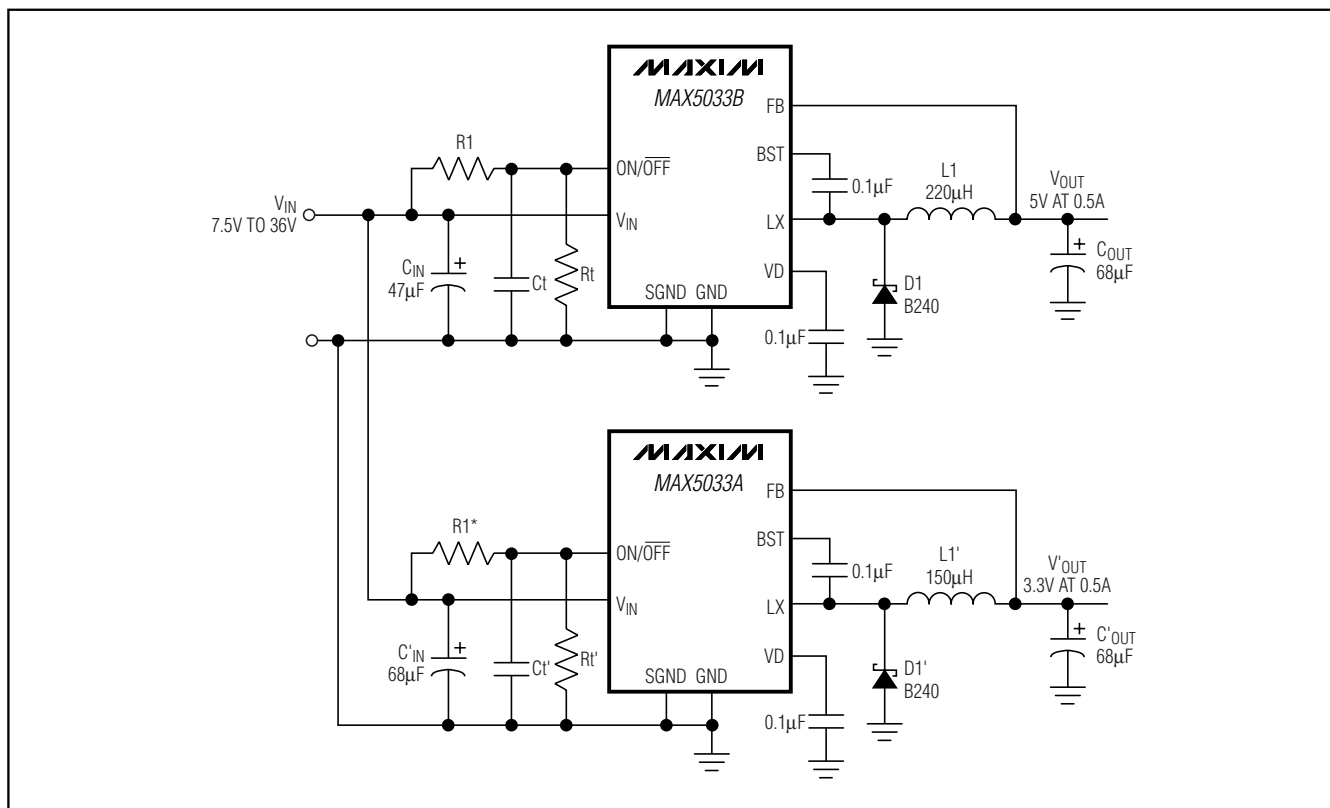


Figure 4. Dual-Sequenced DC-DC Converters (Startup Delay Determined by R_1/R_1' , C_t/C_t' and R_t/R_t')

Chip Information

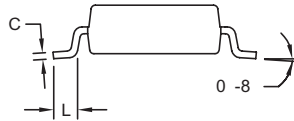
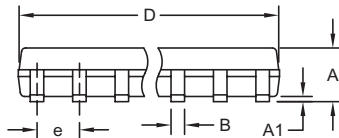
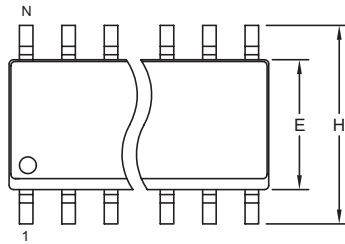
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PROCESS: BICMOS

500mA, 76V, High-Efficiency, MAXPower Step-Down DC-DC Converter

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.053	0.069	1.35	1.75
A1	0.004	0.010	0.10	0.25
B	0.014	0.019	0.35	0.49
C	0.007	0.010	0.19	0.25
e	0.050 BSC		1.27 BSC	
E	0.150	0.157	3.80	4.00
H	0.228	0.244	5.80	6.20
L	0.016	0.050	0.40	1.27

VARIATIONS:

DIM	INCHES		MILLIMETERS		N	MS012
	MIN	MAX	MIN	MAX		
D	0.189	0.197	4.80	5.00	8	AA
D	0.337	0.344	8.55	8.75	14	AB
D	0.386	0.394	9.80	10.00	16	AC

NOTES:

1. D&E DO NOT INCLUDE MOLD FLASH.
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15mm (.006").
3. LEADS TO BE COPLANAR WITHIN 0.10mm (.004").
4. CONTROLLING DIMENSION: MILLIMETERS.
5. MEETS JEDEC MS012.
6. N = NUMBER OF PINS.

 DALLAS SEMICONDUCTOR			
PROPRIETARY INFORMATION			
TITLE:			
PACKAGE OUTLINE, .150" SOIC			
APPROVAL	DOCUMENT CONTROL NO.	REV.	1/
	21-0041	B	1

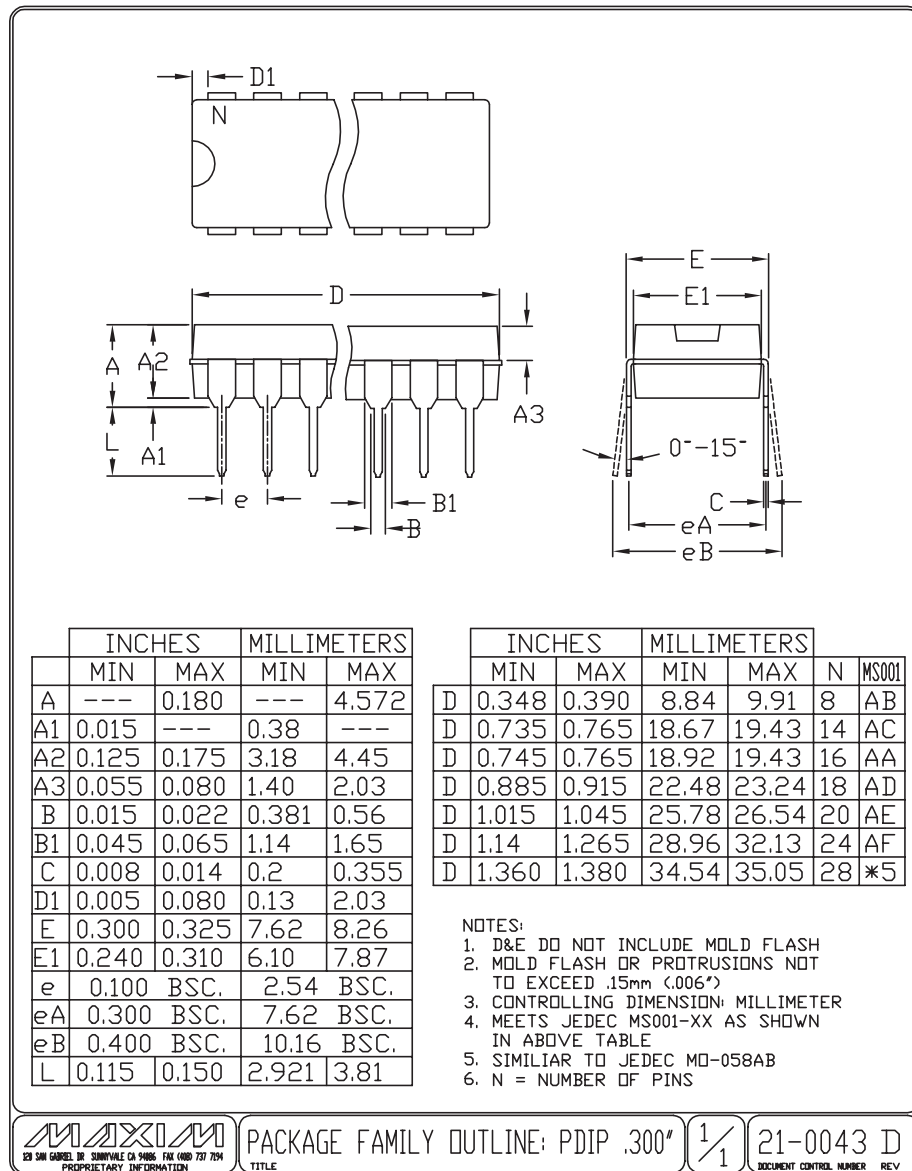
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